# NSN 5962-01-339-1700

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View Online at https://aerobasegroup.com/nsn/5962-01-339-1700

### **Overall Height:**

Between 0.325 inches and 0.400 inches

#### **Body Length:**

1.060 inches

### Body Width:

Between 0.220 inches and 0.310 inches

#### **Body Height:**

Between 0.130 inches and 0.185 inches

### **Maximum Power Dissipation Rating:**

2.0 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Bipolar and monolithic and hermetically sealed and burn in

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

#### Output Logic Form:

Transistor-transistor logic

#### Input Circuit Pattern:

10 input

#### **Case Outline Source And Designator:**

D-8 mil-m-38510

#### **Current Rating Per Characteristic:**

180.00 milliamperes supply

#### **Terminal Surface Treatment:**

Solder

#### **Product Name:**

Registered and-or gate array

#### Voltage Rating And Type Per Characteristic:

-500.0 millivolts power source and 12.0 volts power source

#### **Time Rating Per Chacteristic:**

25.00 nanoseconds propagation delay

#### Memory Device Type:

Programmed

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### **Terminal Type And Quantity:**

20 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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